

Jörgen Olsson received the Ph.D. degree in electronics from Uppsala University, Sweden, in 1996. During 1997 he was a visiting senior scientist at Digital Semiconductors, Hudson, MA, USA. In 2003 he became associate professor (Docent) at Uppsala University. In 2008 he was appointed Professor in Solid-State Electronics, Uppsala University. His research interests are primarily in the fields of high-frequency MOS-based devices and processes, SOI-technology, and RF-power devices. He is also the director of postgraduate studies and the deputy head of the department of engineering sciences. He is author of more than 170 scientific papers in international journals and conferences.